

IN THE CLAIMS:

Please cancel claims 1 and 69-76 without prejudice. Please add the following new claims:

Sub
F1
85. (newly added) The integrated circuit structure of claim 77, wherein the first and second portions of the source and drain regions are both formed of a semiconductor material.

Sub
F1
86. (newly added) The integrated circuit structure of claim 77, wherein the second portions of the source and drain regions each form contact regions for source/drain contacts.